Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

Claims 1-4 (canceled)

- 1 Claim 5 (currently amended): A semiconductor device,
- 2 comprising: combining and disposing means for which is
- 3 formed by combining and disposing pre-registered functional
- 4 blocks, and wiring means for determining a wiring pattern
- 5 in accordance with a given logic circuit specification,
- 6 wherein at least one of the functional blocks has
- 7 <u>comprising:</u>
- 8 a logic circuit, and,
- a diode, the diode which is composed of a first
- 10 conduction type diffusion layer and a second conduction
- 11 type well connected to a power source, and
- 12 wherein the diode is connected to a potential-clamped
- input terminal of the at least one of the functional
- 14 blocks.
- 1 Claim 6 (previously presented): The semiconductor
- 2 device as claimed in Claim 5, wherein the logic circuit is
- a memory.

- 1 Claim 7 (previously presented): A method of designing
- a semiconductor device, comprising the steps of:
- 3 combining and disposing pre-registered functional
- 4 blocks, and
- determining a wiring pattern in accordance with a
- 6 given logic circuit specification,
- 7 wherein at least one of the functional blocks has a
- 8 logic circuit and a diode,
- 9 the diode is composed of a first conduction type
- 10 diffusion layer and a second conduction type well connected
- 11 to a power source, and
- the diode is connected to a potential-clamped input
- 13 terminal of the at least one of the functional blocks.
- 1 Claim 8 (previously presented): A computer-readable
- 2 recording medium, on which the method of designing a
- 3 semiconductor device, as claimed in Claim 7, is stored as
- a program to be executed by a computer.
- 1 Claim 9 (previously presented): A design support
- 2 apparatus for a semiconductor device, comprising:
- 3 combining and disposing means for combining and
- 4 disposing pre-registered functional blocks, and
- 5 wiring means for determining a wiring pattern in
- 6 accordance with a given logic circuit specification,

- 7 wherein at least one of the functional blocks has a
- 8 logic circuit and a diode, and
- wherein the diode is composed of a first conduction
- 10 type diffusion layer and a second conduction type well
- 11 connected to a potential-clamped input terminal of the at
- 12 least one of the functional blocks.
- 1 Claim 10 (currently amended): A semiconductor device,
- 2 comprising: combining and disposing means for combining
- 3 which is formed by combing and disposing pre-registered
- 4 functional blocks, and
- 5 wiring means for determining a wiring pattern in
- 6 accordance with a given logic circuit specification,
- 7 wherein at least one of the functional blocks has a
- 8 logic circuit and a diode which is at least connected to an
- 9 input pin where results of an antenna ratio exceed an
- 10 allowed antenna ratio,
- 11 the diode is composed of a first conduction type
- 12 diffusion layer and a second conduction type well connected
- to a power source, and
- the diode is connected to a potential-clamped input
- terminal of the at least one of the functional blocks.
- 1 Claim 11 (previously presented): The semiconductor
- device as claimed in Claim 10, wherein the logic circuit is
- a memory.

- 1 Claim 12 (previously presented): A method of
- 2 designing a semiconductor device, comprising the steps of:
- 3 combining and disposing pre-registered functional
- 4 blocks, and
- determining a wiring pattern in accordance with a
- 6 given logic circuit specification,
- 7 wherein at least one of the functional blocks has a
- 8 logic circuit and a diode which is at least connected to an
- 9 input pin where results of an antenna ratio exceed an
- 10 allowed antenna ratio,
- wherein the diode is composed of a first conduction
- 12 type diffusion layer and a second conduction type well
- 13 connected to a power source, and
- the diode is connected to a potential-clamped input
- terminal of the at least one of the functional blocks.
- 1 Claim 13 (previously presented): A computer-readable
- 2 recording medium, on which the method of designing a
- 3 semiconductor device, as claimed in Claim 12, is stored as
- a program to be executed by a computer.
- 1 Claim 14 (currently amended): A design support
- apparatus for a semiconductor device[[,]] comprising:
- 3 combining and disposing means for combining and
- 4 disposing pre-registered functional blocks, and

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- 5 wiring means for determining a wiring pattern in
- 6 accordance with a given logic circuit specification,
- 7 wherein at least one of the functional blocks has a
- 8 logic circuit and a diode which is at least connected to an
- 9 input pin where results of an antenna ratio exceed an
- 10 allowed antenna ratio, and
- wherein the diode is composed of a first conduction
- 12 type diffusion layer and a second conduction type well
- 13 connected to a potential-clamped input terminal of the at
- 14 least one of the functional blocks.
- 1 Claim 15 (previously presented): The semiconductor
- 2 device as claimed in Claim 5, wherein the diode is
- 3 connected to a port between an output of the logic circuit
- 4 and the input terminal of the functional block.
- 1 Claim 16 (new): A semiconductor device comprising at
- 2 least one functional block having a logic circuit and a
- 3 diode composed of a first conduction type diffusion layer
- 4 and a second conduction type well connected to a power
- source, wherein the diode is connected to a potential-
- 6 clamped input terminal of the at least one functional
- 7 block.
- 1 Claim 17 (new): The semiconductor device as claimed
- in Claim 16, wherein the logic circuit is a memory.

- 1 Claim 18 (new): The semiconductor device as claimed
- 2 in Claim 16, wherein the diode is connected to a port
- 3 between an output of the logic circuit and the input
- 4 terminal of the functional block.
- 1 Claim 19 (new): A semiconductor device comprising at
- 2 least one functional block having a logic circuit and a
- 3 diode which is at least connected to an input pin where
- 4 results of an antenna ratio exceed an allowed antenna
- s ratio, wherein the diode is composed of a first conduction
- 6 type diffusion layer and a second conduction type well.
- 7 connected to a power source and wherein the diode is
- 8 connected to a potential-clamped input terminal of the at
- 9 least one of the functional blocks.
- 1 Claim 20 (new): The semiconductor device as claimed
- in Claim 19, wherein the logic circuit is a memory.